WHAT IS CLAIMED IS:

1. (Original) An ion-assisted electron beam evaporation process, the process comprising the steps of:

positioning multiple high yield fixtures in an array;

adjusting a vertical position of each of the fixtures to compensate for variations in deposition rate versus chamber location;

providing two electron guns;

mounting the guns to a movable track;

positioning the first gun at a source deposition location;

rotating the fixtures at greater than 2400 rpm;

performing ion assisted evaporation with the first gun, the second gun being kept in a stand-by location in pre-heat mode;

ceasing deposition prior to achieving target thickness;

shuttering each of the fixtures at different times;

independently reopening the fixtures to a low rate pulsed deposition to achieve the target thickness;

closing clam shutters on the fixtures;

moving the first gun to a stand-by position;

moving the second gun to the source deposition location;

sampling evaporation with a quartz crystal thickness monitor;

opening a shutter on the second gun;

performing ion assisted evaporation with the second gun, the first gun being kept in a stand-by location in pre-heat mode;

ceasing deposition prior to achieving target thickness;

shuttering each of the fixtures at different times;

independently reopening the fixtures to a low rate pulsed deposition to achieve the target thickness;

closing clam shutters on the fixtures; and repeating the process until desired filter is obtained.

2. (Original) A method for producing an optical filter utilizing line-of-sight deposition, the method comprising the steps of:

providing multiple substrates;

providing a fixed ion source;

providing at least one selectively movable evaporator;

positioning the at least one evaporator at a source deposition location; and, depositing material onto the substrates.

3. (Original) The method of Claim 2, wherein the method further comprises the step of:

shuttering the substrates as necessary to ensure uniform deposition on the substrates.

4. (Original) The method of Claim 3, where in the method further comprises the step of:

rotating the substrates at approximately greater than 500 revolutions per minute.

- 5. (Original) The method of Claim 4, wherein shuttering the substrates as necessary to ensure uniform deposition on the substrates comprises the steps of: ceasing deposition of a layer prior to achieving target thickness; shuttering the substrates at different times; independently unshuttering the substrates; and, achieving the target thickness.
- 6. (Original) The method of Claim 2, wherein the at least one evaporator is at least two selectively movable evaporators, the method further comprising the steps of: moving the first evaporator to a stand-by position; opening a shutter on the second evaporator; positioning the second evaporator at the source deposition location; and, performing ion assisted evaporation with the second evaporator.
- 7. (Original) The method of Claim 6, wherein the method further comprises the steps of:

ceasing deposition of a layer prior to achieving target thickness; shuttering the substrates at different times; independently unshuttering the substrates; and, achieving the target thickness.

8. (Original) The method of Claim 7, wherein after moving the second evaporator into the source deposition location, the method comprises the step of: sampling evaporation with a quartz crystal thickness monitor.

9. (Original) The method of Claim 8, wherein the method further comprises the steps of:

closing clam shutters on the substrates; and, repeating the process until desired filter is obtained.

10. (Original) The method of Claim 9, wherein providing multiple substrates comprises the step of:

providing a dense high yield fixture array having multiple, independently shutterable fixtures, each of the fixtures containing multiple substrates.

11. (Currently amended) A system for producing optical filters, the system comprising:

multiple substrates;

an ion source;

at least two one selectively movable evaporators; evaporator; and, a source deposition location.

- 12. (Original) The system of Claim 11, wherein the system further comprises: shuttering means for shuttering the substrates; and, a vacuum chamber.
- 13. (Original) The system of Claim 12, wherein the substrates are rotated at approximately greater than 500 revolutions per minute.
- 14. (Original) The system of Claim 13, wherein the substrates are attached to high yield fixtures, the fixtures being independently shutterable.

- 15. (Original) The system of Claim 14, wherein the fixtures rotate and are adjustable.
 - 16. (Original) The system of Claim 15, wherein the system further comprises: a quartz crystal thickness monitor.
- 17. (Original) The system of Claim 16, wherein the evaporators are connected to a movable track, the movable track being opposite the fixtures in the vacuum chamber.
- 18. (Original) The system of Claim 17, wherein the vacuum chamber is approximately 60 inches by 80 inches.
 - 19. (Original) An optical filter produced by the method of Claim 2.
- 20. (Original) The method of Claim 4, wherein rotating the substrates at greater than 500 revolutions per minute comprises the step of:

rotating the substrates at greater than 2400 revolutions per minute.

- 21. (Original) The system of Claim 13, wherein the substrates are rotated at greater than 2400 revolutions per minute.
- 22. (New) The system of Claim 11, wherein the system comprises at least two selectively movable evaporators.